NSN 5961-01-374-8493

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-8493 **Inclosure Material:** Plastic **Overall Length:** Between 2.800 millimeters and 3.040 millimeters **Overall Height:** Between 0.800 millimeters and 1.200 millimeters **Overall Width:** Between 1.200 millimeters and 1.400 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-236aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 200.00 milliamperes all primaries preset **Power Rating Per Characteristic:** 280.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** Between 9.0 and 11.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: